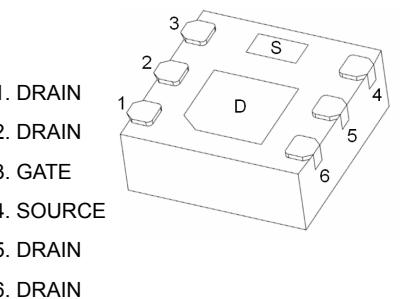


DFNWB2*2-6L-J Plastic-Encapsulate MOSFETS

CJM1206 P-Channel Power MOSFET

V_{(BR)DSS}	R_{DS(on)MAX}	I_D
-12V	45 mΩ@-4.5V	-6A
	60 mΩ@-2.5V	
	90 mΩ@-1.8V	

DFNWB2*2-6L-J



DESCRIPTION

The CJM1206 uses advanced trench technology to provide excellent R_{DS(on)}, low gate charge and operation with low gate voltage.

This device is suitable for use as a load switching application and a wide variety of other applications.

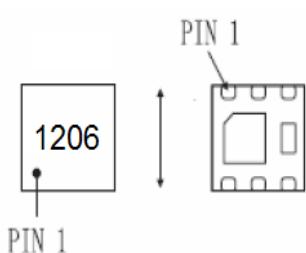
FEATURES

- Advanced trench MOSFET process technology
- Ultra low on-resistance with low gate charge

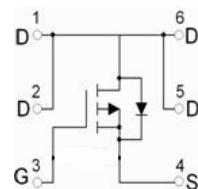
APPLICATIONS

- PWM application
- Load switch
- Battery charge in cellular handset

.....A5 F? =B;



Equivalent Circuit



Maximum ratings (T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-12	V
Gate-Source Voltage	V _{GS}	±8	
Drain Current-Continuous	I _D	-6	A
Drain Current-Pulsed	I _{DM*}	-20	
Thermal Resistance from Junction to Ambient	R _{θJA}	357	°C/W
Junction Temperature	T _j	150	
Storage Temperature	T _{STG}	-55 ~ +150	

*Repetitive rating: Pulse width limited by junction temperature.

MOSFET ELECTRICAL CHARACTERISTICS

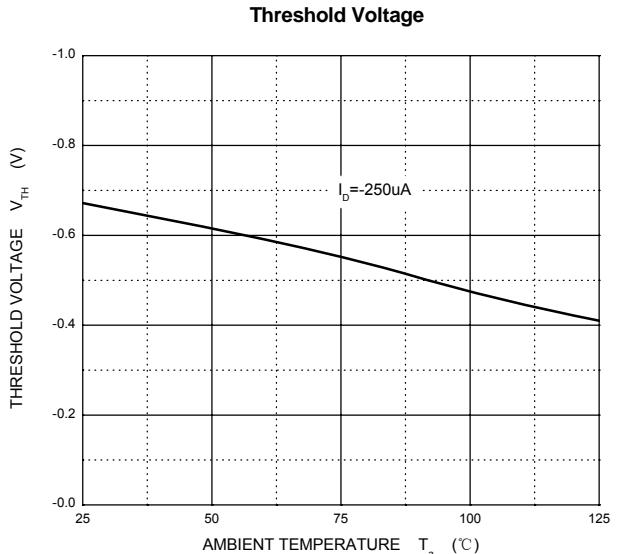
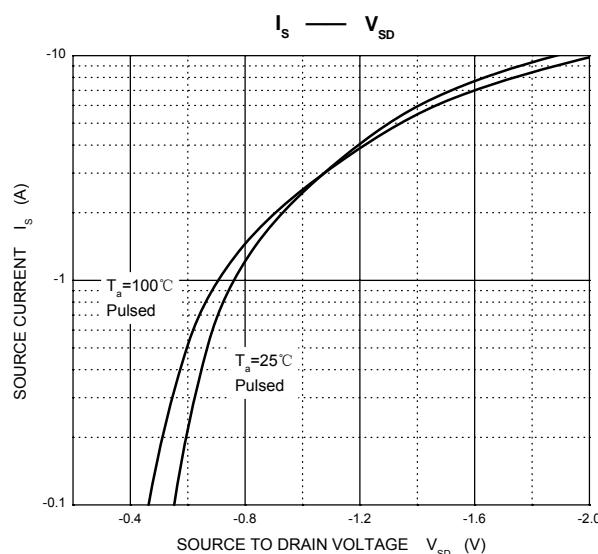
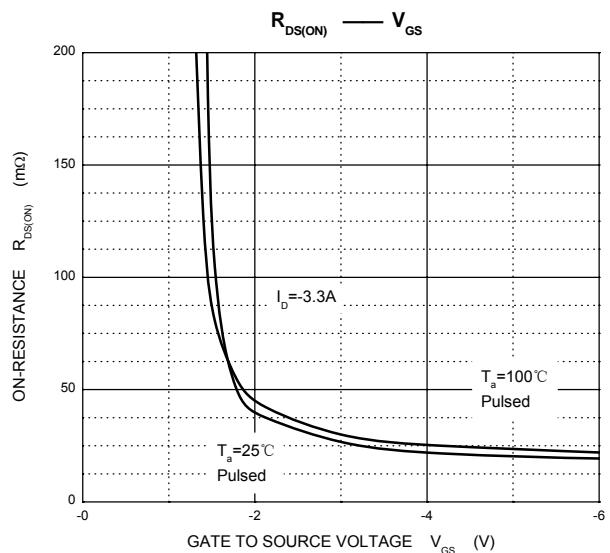
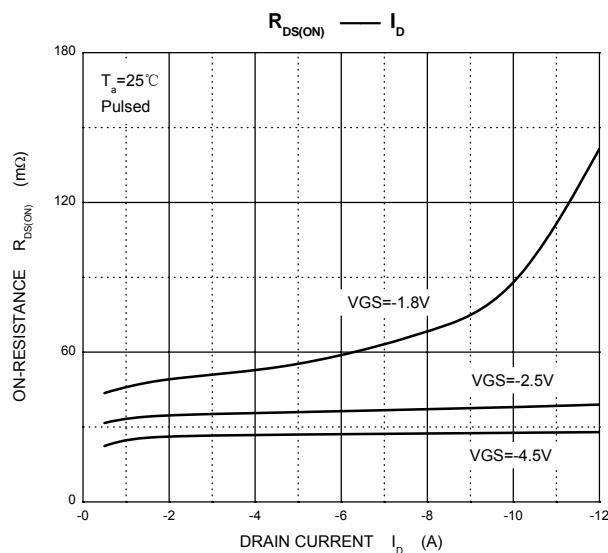
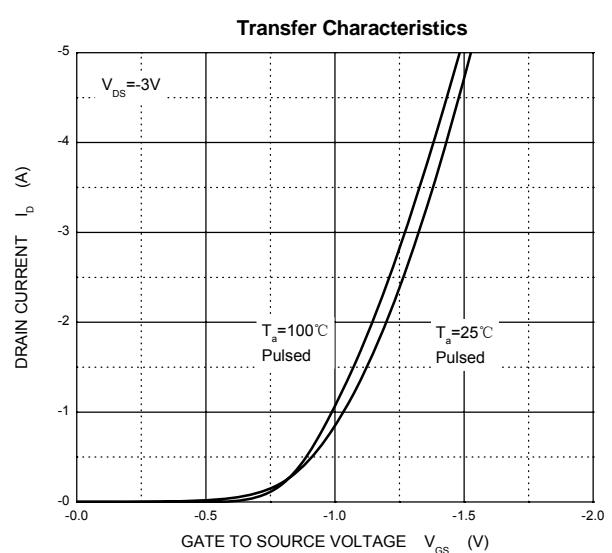
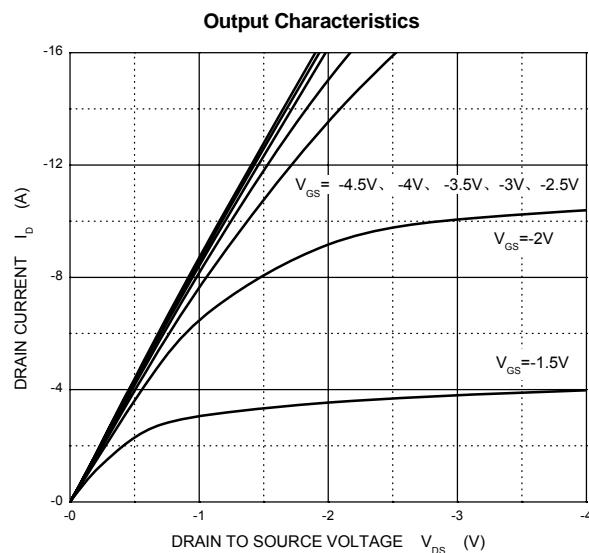
T_a=25 °C unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-12			V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.5		-0.9	
Gate-source leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±8V			±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -8V, V _{GS} = 0V			-1	μA
Drain-source on-state ^a resistance	R _{D(on)}	V _{GS} = -4.5V, I _D = -3.5A		30	45	mΩ
		V _{GS} = -2.5V, I _D = -3A		40	60	
		V _{GS} = -1.8V, I _D = -2.0A		60	90	
Forward transconductance ^a	g _f	V _{DS} = -5V, I _D = -4.1A	6			S
Dynamic						
Input capacitance ^{b,c}	C _{iss}	V _{DS} = -4V, V _{GS} = 0V, f = 1MHz		740		pF
Output capacitance ^{b,c}	C _{oss}			290		
Reverse transfer capacitance ^{b,c}	C _{rss}			190		
Total gate charge ^b	Q _g	V _{DS} = -4V, V _{GS} = -4.5V, I _D = -4.1A		7.8	15	nC
Gate-source charge ^b	Q _{gs}	V _{DS} = -4V, V _{GS} = -2.5V, I _D = -4.1A		4.5	9	
Gate-drain charge ^b	Q _{gd}			1.2		
Gate resistance ^{b,c}	R _g	f = 1MHz	1.4	7	14	Ω
Turn-on delay time ^{b,c}	t _{d(on)}	V _{DD} = -4V, R _L = 1.2Ω, I _D ≈ -3.3A, V _{GEN} = -4.5V, R _g = 1Ω		13	20	ns
Rise time ^{b,c}	t _r			35	53	
Turn-off Delay time ^{b,c}	t _{d(off)}			32	48	
Fall time ^{b,c}	t _f			10	20	
Turn-on delay time ^{b,c}	t _{d(on)}			5	10	
Rise time ^{b,c}	t _r	V _{DD} = -4V, R _L = 1.2Ω, I _D ≈ -3.3A, V _{GEN} = -8V, R _g = 1Ω		11	17	
Turn-off delay time ^{b,c}	t _{d(off)}			22	33	
Fall time ^{b,c}	t _f			16	24	
Drain-source body diode characteristics						
Continuous source-drain diode current	I _S				-6	A
Pulse diode forward current ^a	I _{SM}				-20	
Body ciode voltage	V _{SD}	I _F = -3.3A			-1.2	V

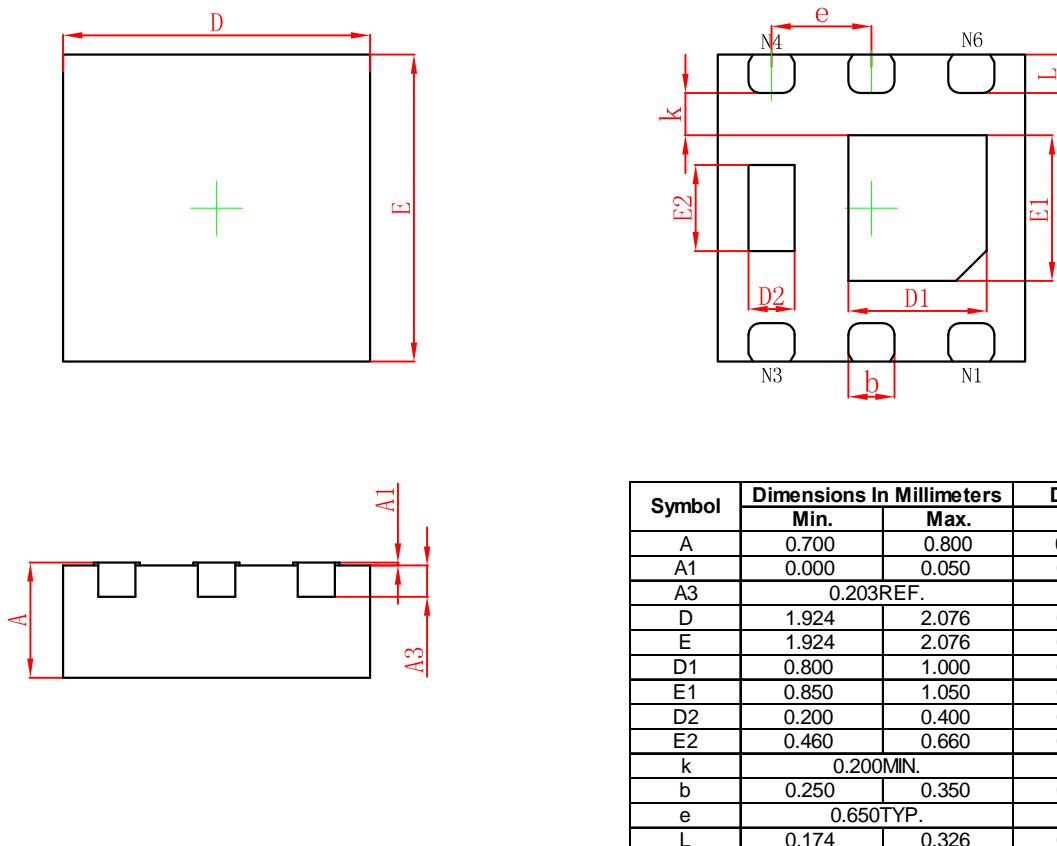
Note :

- a. Pulse Test ; Pulse Width ≤300μs, Duty Cycle ≤2%.
- b. Guaranteed by design, not subject to production testing.
- c. These parameters have no way to verify.

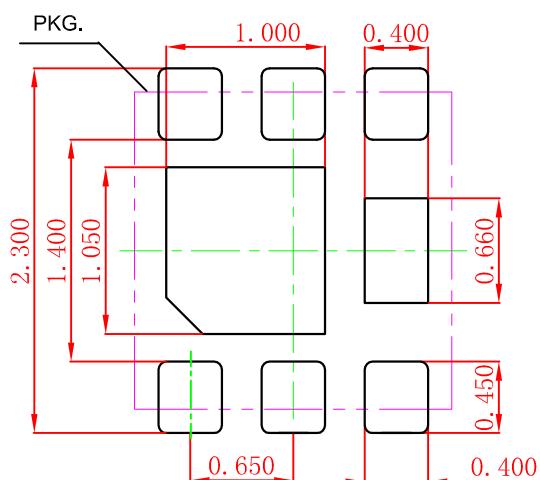
Typical Characteristics



DFNWB2X2-6L-J Package Outline Dimensions



DFNWB2X2-6L-J Suggested Pad Layout



Note:

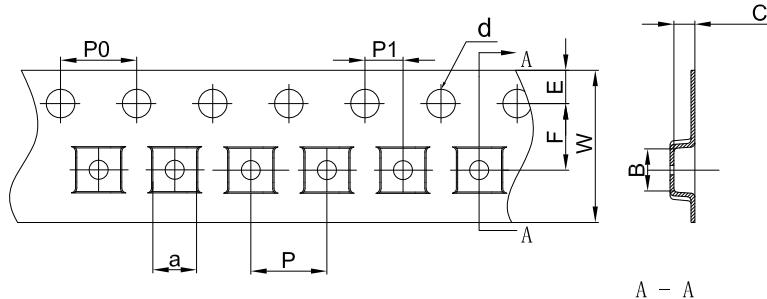
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.050\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

DFNWB2×2-6L Tape and Reel

DFNWB2×2-6L Embossed Carrier Tape

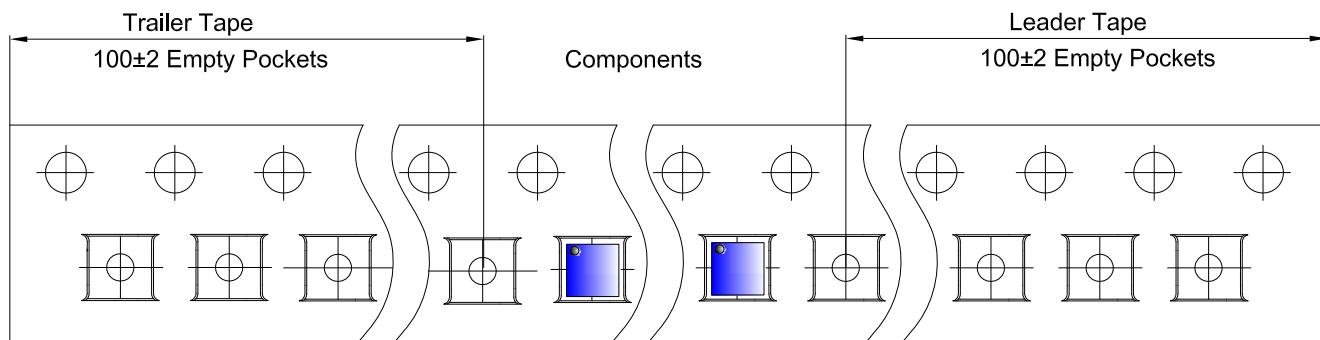


Packaging Description:

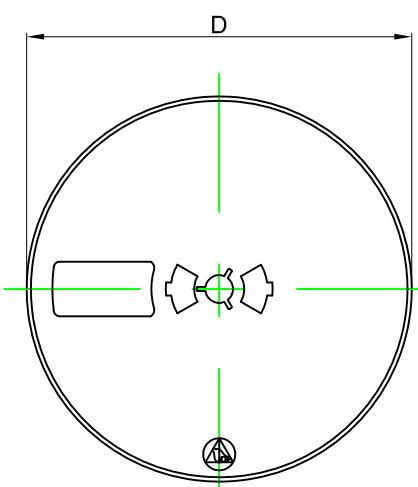
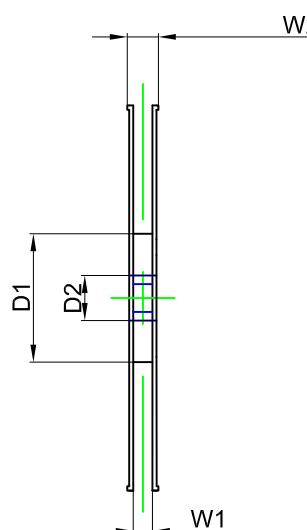
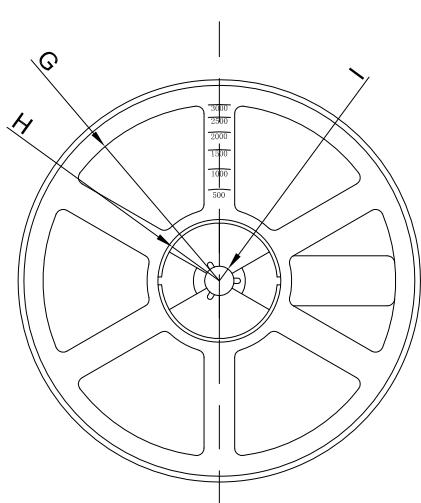
DFNWB2×2-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 18.0cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
DFNWB2×2-6L	2.30	2.30	1.10	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

DFNWB2×2-6L Tape Leader and Trailer



DFNWB2×2-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	